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PTO/SB/21 (08-00)
Approved for use through 10/31/2002. OMB 0651-0031
U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

TRANSMITTAL FORM

(to be used for all correspondence after initial filing)

Application Number	10/646,247
Filing Date	08/22/2003
First Named Inventor	S. S. P. Parkin
Group Art Unit	2811
Examiner Name	to be assigned
Attorney Docket Number	ARC920030071US1

Total Number of Pages in This Submission

ENCLOSURES (check all that apply)

- ☒ Fee Transmittal Form
 - ☐ Fee Attached
- ☐ Amendment / Reply
 - ☐ After Final
 - ☐ Affidavits/declaration(s)
- ☐ Extension of Time Request
- ☐ Express Abandonment Request
- ☒ Information Disclosure Statement
- ☐ Certified Copy of Priority Document(s)
- ☐ Response to Missing Parts/ Incomplete Application
 - ☐ Response to Missing Parts under 37 CFR 1.52 or 1.53

- ☐ Assignment Papers (for an Application)
- ☐ Drawing(s)
- ☐ Licensing-related Papers
- ☐ Petition
- ☐ Petition to Convert to a Provisional Application
- ☐ Power of Attorney, Revocation Change of Correspondence Address
- ☐ Terminal Disclaimer
- ☐ Request for Refund
- ☐ CD, Number of CD(s) _____

- ☐ After Allowance Communication to Group
- ☐ Appeal Communication to Board of Appeals and Interferences
- ☐ Appeal Communication to Group (Appeal Notice, Brief, Reply Brief)
- ☐ Proprietary Information
- ☐ Status Letter
- ☐ Other Enclosure(s) (please identify below):

Remarks

SIGNATURE OF APPLICANT, ATTORNEY, OR AGENT

Firm
or
Individual name

Daniel E. Johnson

Signature

Daniel E. Johnson

Date

04/14/2004

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents, P.O.Box 1450, Alexandria, VA 22313-1450 on this date:

04/14/2004

Typed or printed name

Cheryl G. Ruby

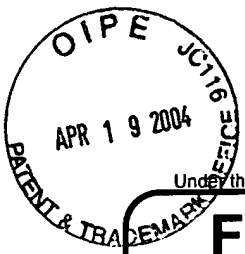
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Cheryl G. Ruby

Date

4/14/04

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FEE TRANSMITTAL for FY 2002

Patent fees are subject to annual revision.

TOTAL AMOUNT OF PAYMENT (\$) 0.00

Complete if Known

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Examiner Name	to be assigned
Group Art Unit	2811
Attorney Docket No.	ARC920030071US1

METHOD OF PAYMENT

- 1.
- ☒
- The Commissioner is hereby authorized to charge indicated fees and credit any overpayments to:

Deposit Account Number	09-0441
Deposit Account Name	IBM CORPORATION

☒ Charge Any Additional Fee Required Under 37 CFR 1.16 and 1.17☐ Applicant claims small entity status. See 37 CFR 1.27

- 2.
- ☐
- Payment Enclosed:

☐ Check ☐ Credit card ☐ Money Order ☐ Other**FEE CALCULATION****1. BASIC FILING FEE**

Large Entity Fee Code (\$)	Small Entity Fee Code (\$)	Fee Description	Fee Paid
101 740	201 370	Utility filing fee	
106 330	206 165	Design filing fee	
107 510	207 255	Plant filing fee	
108 740	208 370	Reissue filing fee	
114 160	214 80	Provisional filing fee	

SUBTOTAL (1) (\$) 0.00

2. EXTRA CLAIM FEES

Total Claims	Extra Claims	Fee from below	Fee Paid
Independent Claims	-20** =	18.00	0.00
Multiple Dependent	-3** =	84.00	0.00

Large Entity Fee Code (\$)	Small Entity Fee Code (\$)	Fee Description
103 18	203 9	Claims in excess of 20
102 84	202 42	Independent claims in excess of 3
104 280	204 140	Multiple dependent claim, if not paid
109 84	209 42	** Reissue independent claims over original patent
110 18	210 9	** Reissue claims in excess of 20 and over original patent

SUBTOTAL (2) (\$) 0.00

**or number previously paid, if greater; For Reissues, see above

FEE CALCULATION (continued)**3. ADDITIONAL FEES**

Large Entity Fee Code (\$)	Small Entity Fee Code (\$)	Fee Description	Fee Paid
105 130	205 65	Surcharge - late filing fee or oath	
127 50	227 25	Surcharge - late provisional filing fee or cover sheet	
139 130	139 130	Non-English specification	
147 2,520	147 2,520	For filing a request for <i>ex parte</i> reexamination	
112 920*	112 920*	Requesting publication of SIR prior to Examiner action	
113 1,840*	113 1,840*	Requesting publication of SIR after Examiner action	
115 110	215 55	Extension for reply within first month	
116 400	216 200	Extension for reply within second month	
117 920	217 460	Extension for reply within third month	
118 1,440	218 720	Extension for reply within fourth month	
128 1,960	228 980	Extension for reply within fifth month	
119 320	219 160	Notice of Appeal	
120 320	220 160	Filing a brief in support of an appeal	
121 280	221 140	Request for oral hearing	
138 1,510	138 1,510	Petition to institute a public use proceeding	
140 110	240 55	Petition to revive - unavoidable	
141 1,280	241 640	Petition to revive - unintentional	
142 1,280	242 640	Utility issue fee (or reissue)	
143 460	243 230	Design issue fee	
144 620	244 310	Plant issue fee	
122 130	122 130	Petitions to the Commissioner	
123 50	123 50	Processing fee under 37 CFR 1.17(q)	
126 180	126 180	Submission of Information Disclosure Stmt	
581 40	581 40	Recording each patent assignment per property (times number of properties)	
146 740	246 370	Filing a submission after final rejection (37 CFR § 1.129(a))	
149 740	249 370	For each additional invention to be examined (37 CFR § 1:129(b))	
179 740	279 370	Request for Continued Examination (RCE)	
169 900	169 900	Request for expedited examination of a design application	

Other fee (specify)

*Reduced by Basic Filing Fee Paid

SUBTOTAL (3) (\$) 0.00

SUBMITTED BY

Name (Print/Type)	Daniel E. Johnson	Registration No. (Attorney/Agent)	37,033	Complete (if applicable) Telephone	408-927-3367
Signature	<i>Daniel E. Johnson</i>	Date	04/14/2004		

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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of : April 14, 2004
S Parkin : Group Art Unit: 2811
Serial No.: 10/646,247 : Examiner: Unknown
Filed: August 22 , 2003 : San Jose, California
Title: MgO-based tunnel spin injectors

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents
U.S. Patent and Trademark Office
P. O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Under the provisions of 37 CFR § 1.97 through §1.99 and pursuant to Applicant's duty of disclosure under 37 CFR §1.56, Applicant respectfully brings the following document(s) listed on the attached form PTO-1449 to the attention of the Examiner in charge of the above-identified application. Copies of the listed document(s) are provided herewith.

This Information Disclosure Statement is being submitted before receiving a first Office Action on the merits for the above-identified patent application. (No fee is due.)

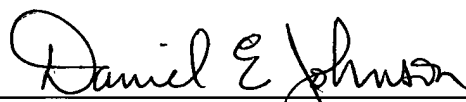
This submission does not constitute an admission that the cited reference(s) are relevant or material to the claims. The reference(s) are only cited as constituting related art of which Applicant is aware.

It is respectfully requested that the listed references be considered by the Examiner and formally made of record in this application.

The Director is hereby authorized to charge payment of any deficiency in the above fee(s) or to charge any additional fees required under 37 CFR § 1.16 or 1.17 or credit any overpayment to Deposit Account No. 09-0441. A duplicate copy of this authorization is attached for the Finance Branch.

Respectfully submitted,

S. Parkin

By 
Daniel E. Johnson (#37,033)
Agent for Applicant
Phone (408) 927-3367

DEJ:cgr

Attachments

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Substitute for form 1449A/PTO				Complete if Known	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)				Application Number	10/646,247
				Filing Date	August 22, 2003
				First Named Inventor	S. Parkin
				Art Unit	2811
				Examiner Name	Unassigned
Sheet	2	of	5	Attorney Docket Number	ARC920030071US1

U.S. PATENT DOCUMENTS					
Examiner Initials [*]	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number - Kind Code ² (if known)			
		US- 2002/0114112 A1	08-22-2002	Nakashio et al.	
		US- 2002/0159203 A1	10-31-2002	Saito et al.	
		US- 2002-0163764 A1	11-07-2002	Nakazawa et al.	
		US- 2002/0164828 A1	11-07-2002	Ishiwata et al.	
		US- 2002/0191355 A1	12-19-2002	Hiramoto et al.	
		US- 2003/0035249 A1	02-20-2003	Ho et al.	
		US- 2003/0058685 A1	03-27-2003	Tran et al.	
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FOREIGN PATENT DOCUMENTS						
Examiner Initials [*]	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		Country Code ³ - Number ⁴ - Kind Code ⁵ (if known)				
		JP 2000 322714	24-Nov-2000	Teruaki et al.	Abstract	

Examiner Signature		Date Considered	
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Applicant's unique citation designation number (optional). ² See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)		Application Number	10/646,247
		Filing Date	August 22, 2003
		First Named Inventor	S. Parkin
		Group Art Unit	2811
		Examiner Name	Unassigned
Sheet 3 of 5	Attorney Docket Number	ARC920030071US1	

OTHER PRIOR ART -- NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
		M. Julliere, "Tunneling Between Ferromagnetic Films", Physics Letters, Vol. 54A, Number 3, September 8, 1975, pp. 225-226.	
		R. Meserve et al., "Spin-Polarized Electron Tunneling", Physics Reports (Review Section of Physics Letters) Vol. 238, No. 4, 1994, pp. 173-243.	
		J. S. Moodera et al., "Large Magnetoresistance at Room Temperature in Ferromagnetic Thin Film Tunnel Junctions", Physical Review Letters, Vol. 74, No. 16, April 17, 1995, pp. 3273-3276.	
		T. Miyazaki et al., "Giant magnetic tunneling effect in Fe/A12O3/Fe junction", Journal of Magnetism and Magnetic Materials, Vol. 139, 1995, pp. L231-L234.	
		D. J. Keavney et al., "Perpendicular conductance and magnetic coupling in epitaxial Fe/MgO/Fe(100) trilayers", J. Appl. Phys., Vol. 81, No. 2, January 15, 1997, pp. 795-798.	
		P. K. Wong et al., "High conductance magnetoresistive tunnel junctions with multiply oxidized barrier", Journal of Applied Physics, Vol. 83, No. 11, June 1, 1998, pp. 6697-6699.	
		E. Y. Tsymbal et al., "Spin-polarized electron tunneling across a disordered insulator", Physical Review B, Vol. 58, No. 1, July 1, 1998-I, pp. 432-437.	
		S.S.P. Parkin et al., "Exchange-biased magnetic tunnel junctions and application to nonvolatile magnetic random access memory (invited)", J. of Applied Physics, Vol. 85, No. 8, April 15, 1999, pp. 5828-5833.	
		K. Aoshima et al., "Thermal deterioration mechanism of CoFeB/PdPtMn Spin valves", J. of Applied Physics, Vol. 85, No. 8, April 15, 1999, pp. 5042-5044.	
		Ph. Mavropoulos et al., "Complex Band Structure and Tunneling through Ferromagnet/Insulator/Ferromagnet Junctions", Phys. Review Letters, Vol. 85, No. 5, July 31, 2000, pp. 1088-1091.	
		D. J. Monsma et al., "Spin polarization of tunneling current from ferromagnet/A12O3 Interfaces using copper-doped aluminum superconducting films", Applied Physics Letters, Vol. 77, No. 5, July 31, 2000, pp. 720-722.	

Examiner Signature		Date Considered	
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¹ Applicant's unique citation designation number (optional). ² Applicant is to place a check mark here if English language Translation is attached.

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				Filing Date	August 22, 2003
				First Named Inventor	S. Parkin
				Group Art Unit	2811
				Examiner Name	Unassigned
Sheet	4	of	5	Attorney Docket Number	ARC920030071US1

OTHER PRIOR ART -- NON PATENT LITERATURE DOCUMENTS			
Examiner Initials	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T ²
		X.-F. Han et al., "Fabrication of high-magnetoresistance tunnel junctions using Co75Fe25 ferromagnetic electrodes", Applied Physics Letters, Vol. 77, No. 2, July 10, 2000, pp 283-285.	
		H. Xi, "Annealing Effect on Exchange Bias in Ni81Fe19/Cr50Mn50 Bilayers", IEEE Transactions on Magnetics, Vol. 36, No. 5, September 2000, pp. 2644-2646.	
		S. Cardoso et al., "High thermal stability tunnel junctions", Journal of Applied Physics, Vol. 87, No. 9, May 1, 2000, pp. 6058-6060.	
		S. Cardoso et al., "Spin-tunnel-junction thermal stability and interface interdiffusion above 300 C", Applied Physics Letters, Vol. 76, No. 5, January 31, 2000, pp. 610-612.	
		M. Takiguchi et al., "Thermal degradation of spin valve multilayers caused by Mn Migration", Journal of Applied Physics, Vol. 87, No. 5, March 1, 2000, pp. 2469-2471.	
		H.L. Meyerheim et al., "Geometrical and Compositional Structure at Metal-Oxide Interfaces: MgO on Fe(001)", Physical Review Letters, Vol. 87, No. 7, August 13, 2001, pp. 076102-1 through 076102-4.	
		M. Bowen et al., "Large magnetoresistance in Fe/MgO/FeCo(001) epitaxial tunnel junctions on GaAs(001)", Applied Physics Letters, Vol. 79, No. 11, Sept. 10, 2001, pp. 1655-1657.	
		W. Wulfskel et al., "Single-crystal magnetotunnel junctions", Applied Physics Letters, Vol. 78, No. 4, Jan. 22, 2001, pp. 509-511.	
		W. H. Butler et al., "Spin-dependent tunneling conductance of Fe/MgO/Fe sandwiches", Physical Review B, Vol. 63, Jan. 8, 2001, pp. 054416-1 through 054416-12.	
		Y. Kim et al., "Magnetoresistance and interlayer diffusion in PtMn spin valves upon postdeposition annealing", J. of Applied Physics, Vol. 89, No. 11, June 1, 2001, pp. 6907-6909.	
		S. Yuasa et al., "Spin-Polarized Resonant Tunneling in Magnetic Tunnel Junctions", Science, Vol. 297, July 12, 2002, pp. 234-237.	

Examiner Signature		Date Considered	
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¹ Applicant's unique citation designation number (optional). ² Applicant is to place a check mark here if English language Translation is attached.

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				Examiner Name	Unassigned
Sheet	5	of	5	Attorney Docket Number	ARC920030071US1

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		E. Popova et al., "Epitaxial MgO layer for low-resistance and coupling-free magnetic tunnel junctions", Applied Physics Letters, Vol. 81, No. 6, August 5, 2002, pp. 1035-1037.	
		M. Tsunoda et al., "60% magnetoresistance at room temperature in Co-Fe/Al-O/Co-Fe tunnel junctions oxidized with Kr-O ₂ plasma", Appl. Phys. Letters, Vol. 80, No. 17, April 29, 2002, pp. 3135-3137.	
		X.-G. Zhang et al., "Effects of the iron-oxide layer in Fe-FeO-MgO-Fe tunneling junctions", Physical Review B, Vol. 68, 2003, pp. 092402-1 through 092402-4.	
		S. Mitani et al., "Fe/MgO/FeCo(100) epitaxial magnetic tunnel junctions prepared by using in situ plasma oxidation", Journal of Applied Physics, Vol. 93, No. 10, May 15, 2003, pp. 8041-8043.	
		J. Faure-Vincent et al., "High tunnel magnetoresistance in epitaxial Fe/MgO/Fe tunnel junctions", Applied Physics Letters, Vol. 82, No. 25, June 23, 2003, pp. 4507-4509.	
		M. Zwierzycki et al., "Spin injection through an Fe/InAs interface", Physical Review B, Vol. 67, 2003, pp. 092401-1 through 092401-4.	
		D. Smith et al., "Structural characterization of thin film ferromagnetic tunnel junctions", Journal of Applied Physics, Vol. 83, No. 10, May 15, 1998, pp. 5154-5158.	
		J. Mathon et al., "Theory of tunneling magnetoresistance of an epitaxial Fe/MgO/Fe (001) junction", Physical Review B, Vol. 63, pp. 220403-1 through 220403-4.	
		M. Klaua et al., "Growth, structure, electronic, and magnetic properties of MgO/Fe(001) bilayers and Fe/MgO/Fe(001) trilayers", Physical Review B, Vol. 64, pp. 134411-1 through 134411-8.	

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